



SAM™ Data Sheet SAM-2800-12-10ps-x, λ = 2800 nm

 $\lambda = 2800 \text{ nm}$ Laser wavelength

High reflection band λ = 2680 .. 2920 nm

Absorbance $A_0 = 12 \%$ $\Delta R = 8 \%$ Modulation depth $A_{ns} = 4 \%$ Non-saturable loss

Saturation fluence $\Phi_{\text{sat}} = 30 \, \mu \text{J/cm}^2$

Relaxation time constant $\tau \sim 10 \text{ ps}$

 $\Phi_{\text{sat}} = 1.2 \text{ mJ/cm}^2$ Damage threshold

4.0 mm x 4.0 mm; other dimensions on request Chip area

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

unmounted $\mathbf{x} = 0$

glued on a gold plated Cu-cylinder with 12.7 mm \varnothing x = 12.7 gx = 25.4 gglued on a gold plated Cu-cylinder with 25.4 mm \varnothing soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing x = 12.7 sx = 25.4 ssoldered on a gold plated Cu-cylinder with 25.4 mm \varnothing x = FCmounted on a 1 m single mode fiber cable with FC connector

Low intensity spectral reflectance

